Features

- Temperature and Voltage Compensated Frequency
- Warning Indication of Lamp Failure by Means of Frequency Doubling only in Direction Mode
- Voltage Dependence of the Car Indicator Lamps also Compensated for Lamp Failure
- Relay Output with High Current-carrying Capacity and Low Saturation Voltage
- Load-dump Protection
- Minimum Lamp Load for Flasher Operation ≥ 1 W
- Low Susceptibility to EMI
- Extremely Low Standby Current of 10 μA
- Protection According to ISO/TR 7637/1 Level 4 with External Capacitor (C2)

Description

The U6432B is an advanced automotive flasher IC which provides low standby current. Its basic function is equal to Atmel's flasher IC U6043B but low current consumption and frequency doubling disabling make outstanding differences.



Low-power Flasher IC with 18-mΩ Shunt

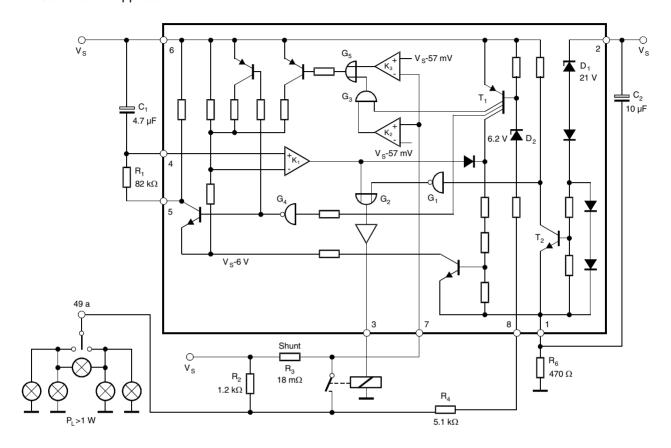
U6432B





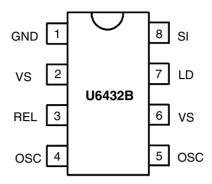
Block Diagram

Figure 1. Car Flasher Application



Pin Configuration

Figure 2. Pinning



Pin Description

Pin	Symbol	Function
1	GND	IC ground
2	VS	Supply voltage
3	REL	Relay driver
4	OSC	Oscillator
5	OSC	Oscillator
6	VS	Supply voltage
7	LD	Lamp failure detection
8	SI	Start input (49a)





Functional Description

Pin 1, GND

The U6432B is protected against damage in case of battery reversal via resistor R_4 to ground (-31). An integrated protection circuit together with external resistances R_2 and R_4 limits the current pulses in the IC.

Pin 2, Supply Voltage, V_S power

The arrangement of the supply connections to Pin 2 (and 6) must be so as to ensure that on the connection printed circuit board (PCB), the resistance of V_S to Pin 6 is lower than that to Pin 2.

Pin 3, Relay Control Output (Driver)

The relay control output is a high-side driver with a low saturation voltage. It is capable of driving a typical automotive relay with a minimum coil resistance of 60 Ω .

Pin 4 and 5, Oscillator

The flashing frequency, f_1 , is determined by the R_1C_1 components as given by the formula below (see Figure 1):

$$f_1 \approx \frac{1}{R_1 \times C_1 \times 1.5} Hz$$

where $C_1 \le 47 \ \mu F$, $R_1 = 6.8 \ k\Omega$ to 510 $k\Omega$

In case of a lamp outage (see Pin 7) the oscillator frequency is switched to the lamp outage frequency f_2 with $f_2 \approx 2.2 \times f_1$.

Duty cycle in normal flashing mode: 50%

Duty cycle in lamp outage mode: 40% (bright phase)

Pin 6, Supply Voltage, Sense

For accurate monitoring via the shunt resistor, a minimized layer resistance from point V_s /shunt to Pin 6 is recommended.

Pin 7

Control Signal Threshold (49 mV Comparator)

The detection point for lamp failure can be calculated from the control signal threshold, typically 49 mV with $V_S=12$ V. With a measuring resistance of $R_3=18$ m Ω , the frequency change-over is reached at a lamp load of 21 W + 11.4 W. The variation of the control signal threshold supply voltage takes into account the PTC characteristic of filament lamps.

Control Signal Threshold 2 (15-mV Comparator)

A voltage drop at the shunt resistor R_3 between 49 mV and 15 mV lets the flasher work in frequency doubling mode.

If the voltage drop decreases to a value below $V_{R3MAX} = 15$ mV, frequency doubling is disabled.

This can be achieved either with a switch which by-passes the shunt resistor (e.g., a special hazard warning switch) or with a small lamp load.

Flasher operation starts with a lamp load of $P_L \ge 1$ W.

Pin 8, Start Input

Start condition for flashing:

- Voltage at Pin 8 (see Figure 1)
- $\bullet \qquad V_8 \leq V_S \text{ } (V_{BE(T1)} + V_{Z(D2)})$

Condition for standby:

The resistor R_2 betwen V_S and Pin 8 provides an extremly low standby current ($I_S \le 10~\mu A$). The leakage current depends on the pull-up resistor R_2 according to the following formula:

$$I_{Leak} \approx (V_{BE(T1)} + V_{Z(D2)})/R_2$$

Application Hint

In order to achieve a high-level immunity against "electrical interference by conduction and coupling" according to ISO/TR 7637/1 test level 4, an electrolythic capacitor C_2 = 10 μF (25 V) between Pin 1 and 2 – mounted close to the IC – is highly recommended.

Absolute Maximum Ratings

Reference point Pin 1

Parameters		Symbol	Value	Unit	
Supply voltage Pin 2 and 6		V _S	18	V	
Surge Forward Currer	nt	•			
$t_p = 0.1 \text{ ms}$ $t_p = 300 \text{ ms}$ $t_p = 300 \text{ ms}$	Pin 2 and 6 Pin 2 and 6 Pin 8	I _{FSM} I _{FSM} I _{FSM}	1.5 1.0 30	A A mA	
Output current	Pin 3	Io	0.3	Α	
Power Dissipation		•			
$T_{amb} = 95^{\circ}C$ $T_{amb} = 60^{\circ}C$	DIP 8 SO8 DIP 8 SO8	P _{tot} P _{tot} P _{tot} P _{tot} P _{tot}	420 340 690 560	mW mW mW mW	
Junction temperature		T _J	150	°C	
Ambient temperature ra	ange	T _{amb}	-40 to +105		
Storage temperature ra	nge	T _{stg}	-55 to +150 °C		





Electrical Characteristics

 T_{amb} = 25°C; typical values under normal operation in application circuit Figure 1, V_S = 12 V (Pins 2 and 6); reference point ground (-31), unless otherwise specified.

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Supply voltage range	Pin 2 and 6	Vs	9		16.5	V
Supply current, dark phase	Pins 2 and 6	Is		4.5	8	mA
Supply current, stand-by	Pins 2 and 6	Is			10	mA
Supply current, bright phase	Pins 2 and 6	Is		7.0	11	mA
Relay output, saturation voltage	I _O = 150 mA V _S = 9 V, Pin 3	V _O			1.0	V
Relay output reverse current	Pin 3	Io			0.1	mA
Relay coil resistance		R_L	60			Ω
Start delay	First bright phase	t _{on}			10	ms
Frequency determining resistor		R ₁	6.8		510	kΩ
Frequency determining capacitor		C ₁			47	μF
Frequency tolerance	Normal flashing, basic frequency f ₁ not including the tolerances of the external components R ₁ and C ₁	Δf_1	-5		+5	%
Bright period	Basic frequency f ₁ V _S = 9 to 15 V	Δf_1	47		53	%
Bright period	Control frequency f ₂ V _S = 9 to 15 V	Δf_2	37		45	%
Frequency increase	Lamp failure, V _S = 9 to 15 V	f ₂	$2.15 \times f_1$		$2.3 \times f_1$	Hz
Control signal threshold 1	V _S = 15 V V _S = 9 V V _S = 12 V, Pin 7	V_{R3}	50 43 47	53 45 49	57 47 51	mV
Control signal threshold 2		V _{R3}			15	mV
Lamp load		P_L	1			W

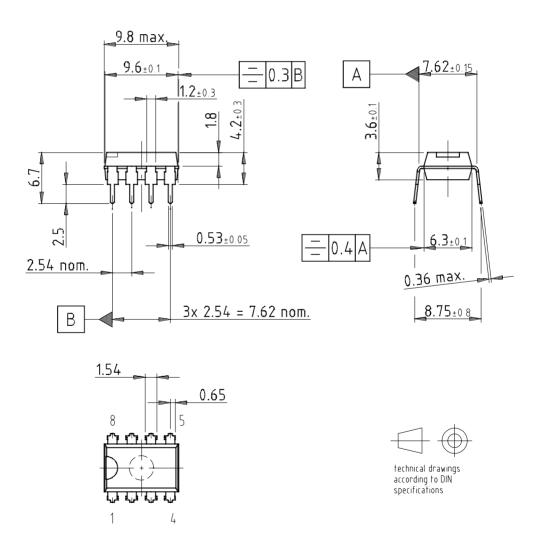
Ordering Information

Extended Type Number	Package	Remarks
U6432B	DIP8	_
U6432B-FP	SO8	_

Package Information

DIP8

Package: DIP 8
Dimensions in mm



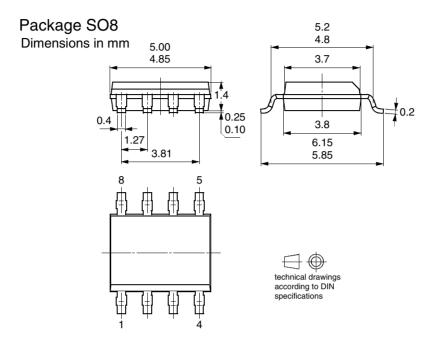
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Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131 Tel: 1(408) 441-0311 Fax: 1(408) 487-2600

Regional Headquarters

Europe

Atmel Sarl Route des Arsenaux 41 Case Postale 80 CH-1705 Fribourg Switzerland

Tel: (41) 26-426-5555 Fax: (41) 26-426-5500

Asia

Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimshatsui East Kowloon Hong Kong Tel: (852) 2721-9778

Tel: (852) 2721-9778 Fax: (852) 2722-1369

Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan

Tel: (81) 3-3523-3551 Fax: (81) 3-3523-7581

Atmel Operations

Memory

2325 Orchard Parkway San Jose, CA 95131 Tel: 1(408) 441-0311 Fax: 1(408) 436-4314

Microcontrollers

2325 Orchard Parkway San Jose, CA 95131 Tel: 1(408) 441-0311 Fax: 1(408) 436-4314

La Chantrerie BP 70602 44306 Nantes Cedex 3, France Tel: (33) 2-40-18-18-18 Fax: (33) 2-40-18-19-60

ASIC/ASSP/Smart Cards

Zone Industrielle 13106 Rousset Cedex, France Tel: (33) 4-42-53-60-00 Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 Tel: 1(719) 576-3300

Tel: 1(719) 576-3300 Fax: 1(719) 540-1759

Scottish Enterprise Technology Park Maxwell Building East Kilbride G75 0QR, Scotland

Tel: (44) 1355-803-000 Fax: (44) 1355-242-743

RF/Automotive

Theresienstrasse 2 Postfach 3535 74025 Heilbronn, Germany Tel: (49) 71-31-67-0 Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906

Tel: 1(719) 576-3300 Fax: 1(719) 540-1759

Biometrics/Imaging/Hi-Rel MPU/ High Speed Converters/RF Datacom

Avenue de Rochepleine BP 123

38521 Saint-Egreve Cedex, France

Tel: (33) 4-76-58-30-00 Fax: (33) 4-76-58-34-80

e-mail
literature@atmel.com

Web Site

http://www.atmel.com

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